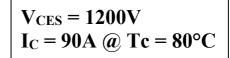
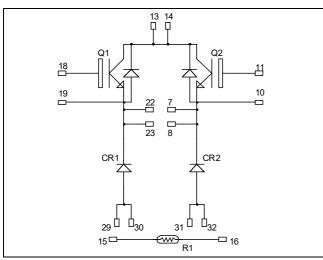


Dual Buck chopper Trench + Field Stop IGBT4 Power module





All multiple inputs and outputs must be shorted together Example: 13/14; 29/30; 22/23 ...

Application

- AC and DC motor control
- Switched Mode Power Supplies

Features

- Trench + Field Stop IGBT 4
 - Low voltage drop
 - Low leakage current
 - Low switching losses
 - Low leakage current
 - RBSOA and SCSOA rated
 - Kelvin emitter for easy drive
- Very low stray inductance
- Internal thermistor for temperature monitoring

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- Easy paralleling due to positive TC of VCEsat
- Each leg can be easily paralleled to achieve a single buck of twice the current capability
- RoHS compliant

All ratings @ $T_j = 25^{\circ}C$ unless otherwise specified

Absolute maximum ratings (per IGBT)

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Voltage		1200	V
Ţ	Continuous Collector Current	$T_c = 25^{\circ}C$	110	
$I_{\rm C}$	Continuous Conector Current	$T_c = 80^{\circ}C$	90	A
I_{CM}	Pulsed Collector Current	$T_c = 25^{\circ}C$	150	
V_{GE}	Gate – Emitter Voltage		±20	V
P_D	Power Dissipation	$T_c = 25$ °C	385	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 150$ °C	150A @ 1150V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.



Electrical Characteristics (per IGBT)

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V ; V_{CE} = 1200V$				250	μA
17	C-11t Eitt C-tti V-1t	$V_{GE} = 15V$	$T_j = 25^{\circ}C$		1.85	2.25	V
$V_{CE(sat)}$	Collector Emitter Saturation Voltage	$I_C = 75A$	$T_j = 150$ °C		2.25		V
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 3 \text{ mA}$		5	5.8	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GF} = 20 \text{ V}, V_{CF} = 0 \text{ V}$,	600	nA

Dynamic Characteristics (per IGBT)

•	Characteristic (per 1981)	Test Conditions		Min	Typ	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$ $V_{CE} = 25V$ $f = 1MHz$			4.4		
Coes	Output Capacitance				0.29		nF
C_{res}	Reverse Transfer Capacitance				0.24		
Q_{G}	Gate charge	V_{GE} = ±15V ; V_{CE} =600V I_{C} =75A			0.57		μС
T _{d(on)}	Turn-on Delay Time	Inductive Switching (25°C)			130		
T _r	Rise Time	$V_{GE} = \pm 15V$			20		ns
T _{d(off)}	Turn-off Delay Time	$V_{\text{Bus}} = 600V$ $I_{\text{C}} = 75A$			300		
T_{f}	Fall Time	$R_G = 2.2\Omega$			45		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switch	ching (150°C)		150		
Tr	Rise Time	$V_{GE} = \pm 15V$			35		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 600\text{V}$ $I_{\text{C}} = 75\text{A}$			350		ns
T_{f}	Fall Time	$R_G = 2.2\Omega$			80		
Е	Turn on Cryitahing Enguery	$V_{GE} = \pm 15V$	$T_J = 25^{\circ}C$		3.3		mJ
Eon	Turn-on Switching Energy	$V_{\text{Bus}} = 600 \text{V}$			8.5		1113
$E_{\rm off}$	Turn-off Switching Energy	$I_C = 75A$	$T_J = 25^{\circ}C$		4.2		mJ
Loff	Turn-on Switching Energy	$R_G = 2.2\Omega$	$T_J = 150$ °C		7.2		1113
I_{sc}	Short Circuit data	$V_{GE} \le 15V ; V_{Bus} = 900V$ $t_p \le 10\mu s ; T_j = 150^{\circ}C$			300		A
R_{thJC}	Junction to Case Thermal Resistance					0.39	°C/W

Chopper diode ratings and characteristics (per diode)

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Peak Repetitive Reverse Voltage					1200	V
I_{RM}	Reverse Leakage Current	$V_R = 1200V$				100	μA
I_F	DC Forward Current		$Tc = 80^{\circ}C$		100		A
		$I_F = 100A$			2.4	3	V
V_{F}	Diode Forward Voltage	$I_F = 150A$			2.7		
		$I_F = 100A$	$T_j = 125$ °C		1.8		
4	Daviana Basavani Tima		$T_j = 25$ °C		385		
t_{rr}	Reverse Recovery Time	$I_F = 100A$ $V_R = 800V$	$T_j = 125$ °C		480		ns
Qrr	Reverse Recovery Charge	$di/dt = 200 A/\mu s$	$T_j = 25^{\circ}C$		1055		C
			$T_j = 125$ °C		5240		пC
R_{thJC}	Junction to Case Thermal Resistance					0.55	°C/W



Thermal and package characteristics

Symbol	Characteristic			Min	Max	Unit	
V_{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000		V	
T_{J}	Operating junction temperature range			-40	175		
T_{JOP}	Recommended junction temperature under switching conditions			-40	T _J max -25	°C	
T_{STG}	Storage Temperature Range			-40	125		
$T_{\rm C}$	Operating Case Temperature			-40	125		
Torque	Mounting torque	To heatsink	M4	2	3	N.m	
Wt	Package Weight			110	g		

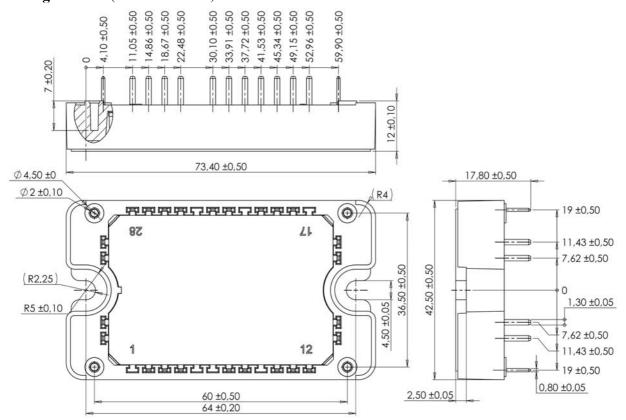
Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic		Min	Typ	Max	Unit
R ₂₅	Resistance @ 25°C	C		50		kΩ
$\Delta R_{25}/R_{25}$				5		%
B _{25/85}	$T_{25} = 298.15 \text{ K}$			3952		K
$\Delta \mathrm{B/B}$		T _C =100°C		4		%

$$R_T = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$

$$R_T: \text{ Thermistor value at T}$$

Package outline (dimensions in mm)

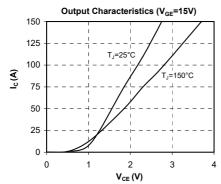


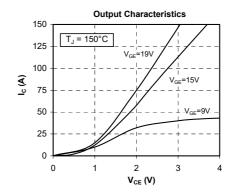
See application note 1906 - Mounting Instructions for SP3F Power Modules on www.microsemi.com

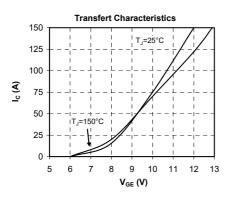
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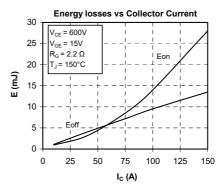


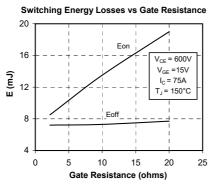
Typical Performance Curve

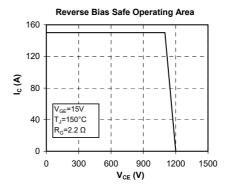


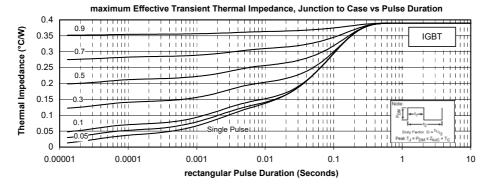




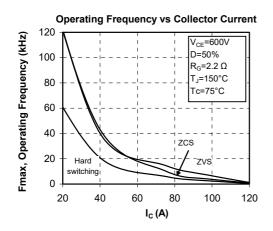


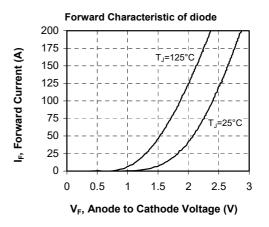


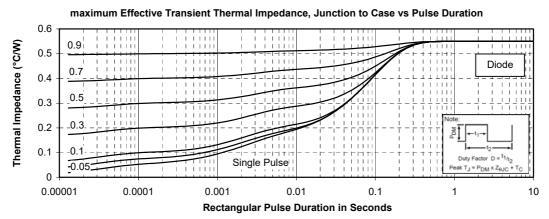












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